

MDL-N-808/7000~10000mW

INFRARED DIODE LASER AT 808nm





Diode infrared laser module at 808nm is made features of ultra compact, long lifetime, low cost and easy operating, which is used in measurement, communication, spectrum analysis, etc.



SPECIFICATIONS

Wavelength (nm)	808±3		
Output power (mW)	>7000, 7100, 7200, ..., 10000		
Transverse mode	Near TE ₀₀		
Operating mode	CW		
Power stability (rms, over 4 hours)	<1%, <3%, <5%		
Warm-up time (minutes)	<5		
M ² factor	<20		
Beam divergence, full angle (mrad)	<3.0		
Beam diameter at the aperture (mm)	5~8		
Beam height from base plate (mm)	68.2		
Pointing stability after warm-up (mrad)	<0.05		
Operating temperature (°C)	10~35		
Power supply (90-264VAC)	PSU-H-LED	PSU-H-FDA	PSU-N-OEM
Modulation option	TTL/Analog 1Hz-5KHz, 1Hz-10KHz, 1Hz-30KHz, and TTL on/off		
Expected lifetime (hours)	10000		
Warranty period	1 year		



MDL-N-808	PSU-H-LED	PSU-H-FDA	PSU-N-OEM
 <p>240(L)×99(W)×94(H) mm³, 2.6 kg</p>	 <p>268 (L) ×145(W) ×106 (H) mm³, 2.6 kg</p>	 <p>238 (L) ×146(W) ×102 (H) mm³, 2.3 kg</p>	 <p>215 (L) ×129 (W) ×122 (H) mm³, 2.145 kg</p>
